NSN 5961-01-522-5306

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-522-5306 **Inclosure Material:** Metal **Overall Length:** Between 0.790 inches and 0.810 inches Overall Width: Between 0.253 inches and 0.267 inches **End Application:** An/tpn-30a, marine remote aircraft landing **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to emitter voltage, dc with base short-circuited to emitter and 55.0 collector to base voltage/static/emitter open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.250 milliamperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector megawatts **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Product Name:** Microwave power transistor npn silicon, 960-1215 mhz **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: